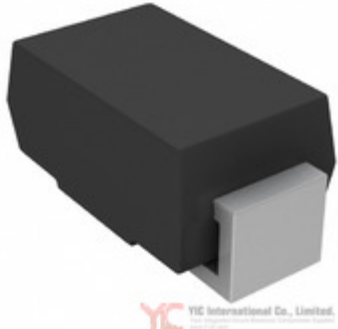

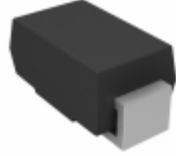
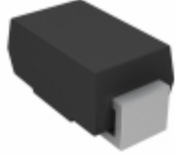
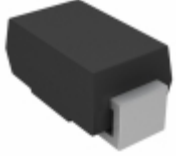
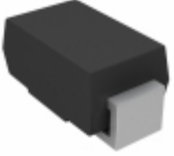
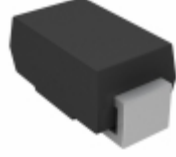
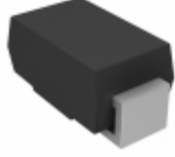
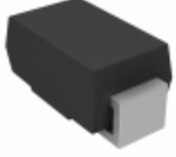
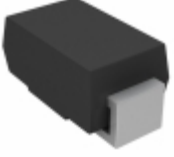
	<p><b>S1JHE3_AI</b></p>
	<p><b>Hersteller-Teilenummer:</b> S1JHE3_AI</p>
	<p><b>Hersteller / Marke:</b> Vishay / Semiconductor - Diodes Division</p>
	<p><b>Teil der Beschreibung:</b> DIODE GEN PURP 600V 1A DO214AC</p>
	<p><b>Datenblätter:</b>  <a href="#">S1JHE3_AI.pdf</a></p>
	<p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>
	<p><b>Lagerzustand:</b> New original, 7500 pcs Stock Available.</p>
	<p><b>Liefern von:</b> Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>

### Spezifikationen

Teilenummer	S1JHE3_AI
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 600V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	7500 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 600V
Spannung - Sperr (Vr) (max)	600V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

S1JHE3\_AI ist neu im Original, Suche S1JHE3\_AI Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1JHE3\_AI Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S1JHE3\_AI: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>S1JHE3_AI</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p><b>S1JHE3/5AT</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p><b>S1JHE3_A/H</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p><b>S1JHE3_A/H</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>
 <p><b>S1JHM3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p><b>S1JHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 600V 1A DO214AC</p>	 <p><b>S1JHM3/61T</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>	 <p><b>S1JHE3/61T</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 600V 1A DO214AC</p>

### heiße Teile

Mehr

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D S1J-004HE3/5AT	S1J-13-F	S1J-13-G-72	S1J-6605E3/11	S1J-6605HE3/61T
S1J-6906/11T	S1J-6906E3/61T	S1J-6906HE3/61T	S1J-E3/11T	S1J-E3/5AT
S1J-E3/5AT	S1J-E3/61T	D S1J-E3/61T	S1J-M3/61T	S1J-M3/61T
S1JA-E3/61T	D S1JA-E3/61T	S1JB-13-F	S1JHE3/5AT	S1JHE3/5AT
S1JHE3/61T	S1JHE3/61T	S1JHE3_AI	SAA7113H	SEMIX353GD126HDS
SPX29301T5-L	SSM3J305T	T1589N20TOF	D TD46N08LOF	TESVA1V224K18R
TP0606N3-G	UCC25705D	VI-22Z-CW	VI-251-IU-BM	XC62HR2702PR

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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